

IXTH3N100P

IXTH3N100P Information

	Part Number Manufacturer Category	
	Description	MOSFET N-CH 1000V 3A TO-247
-	Package	TO-247-3
		For the pricing/inventory/lead time, please contact
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IXTH3N100P Specifications

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Manufacturer Part Number	IXTH3N100P
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	PolarVHV?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	1000V
Current - Continuous Drain (Id) @ 25°C	3A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	39nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1100pF @ 25V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	125W (Tc)
Rds On (Max) @ Id, Vgs	4.8 Ohm @ 1.5A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-247 (IXTH)
Package / Case	TO-247-3
	Report errors?

IXTH3N100P Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE SUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IXTH3N100P Payment Methods



IXTH3N100P Shipping Methods



If you have any question about IXTH3N100P, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com